nexperia

Quarterly Reliability Monitoring Results

Quarters: Q1/2021 to Q4/2021

Based on	structural	similarity
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Supplier		User Part Number					
Nexperia B.V.		PMEG4010CEA					
Name of Laboratory		Part Description					
		Nexperia DHAM	Schottky				
Assembly reliability labs		SMD package					
Based on AEC-Q101 Test		Test Conditions	Duration	# Lots	# Quantity	# Rejects	
	TEST						
	Pre- and Post-Stress						
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below	
		JESD22-A113					
		Bake Tamb = 125 °C	24 hours				
	PC	Soak Tamb = 85 °C, RH = 85%	168 hours				
# A1	Preconditioning	Reflow soldering	3 cycles	810	58300	0	
		MIL-STD-750-1					
	HTRB	M1038 Method A					
	High Temperature Reverse						
# B1	Bias	reverse voltage ^[1]	1000 hours	116	9280	0	
	тс	JESD22-A104					
# A4	Temperature Cycling	-65 °C to Timax, not to exceed 150°C	1000 cycles	170	12600	0	
# A4	Temperature Cycling	5	1000 cycles	170	13600	0	
	AC	JESD22-A102 Tamb = 121 °C, RH = 100 %					
# AD - It	Autoclave	Pressure = $205 \text{ kPa} (29.7 \text{ psia})$		170	12600	0	
# A3 alt	Autoclave	Plessure = 203 kPa (29.7 psia)	96 hours	170	13600	0	
	H3TRB	JESD22-A101					
	H31RB High Humidity High	Tamb = $85 ^{\circ}$ C, RH = 85% , VR = 80% of					
# A2 alt		rated reverse voltage ^{[1], [2]}	1000 hours	170	13600	0	
# AZ dIL	remperature Reverse blas		1000 Hours	170	13000	U	
	IOL	MIL-STD-750 Method 1037					
# AF	IOL Intermittent Operating Life	ton = toff, devices powered to insure ΔT_j = 100 °C for 15000 cycles	1000 hours	170	12600	0	
# A5	Internittent Operating Life		1000 hours	170	13600	0	
	RSH	JESD22-A111					
# C8	Resistance to Solder Heat		10 s	130	3900	0	
# 0	SD	200 0 = 5 0	10.2	130	2300	U	
# C10	Solderability	J-STD-002		262	2620	0	
		des have to be considered (thermal runaway).		363	3630	0	

[1] The physical limitations of Schottky diodes have to be considered (thermal runaway).

[2] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia DHAM	Schottky	9280	0	0.46	2.19E+09
	Beneticity	200	5		21152.05

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